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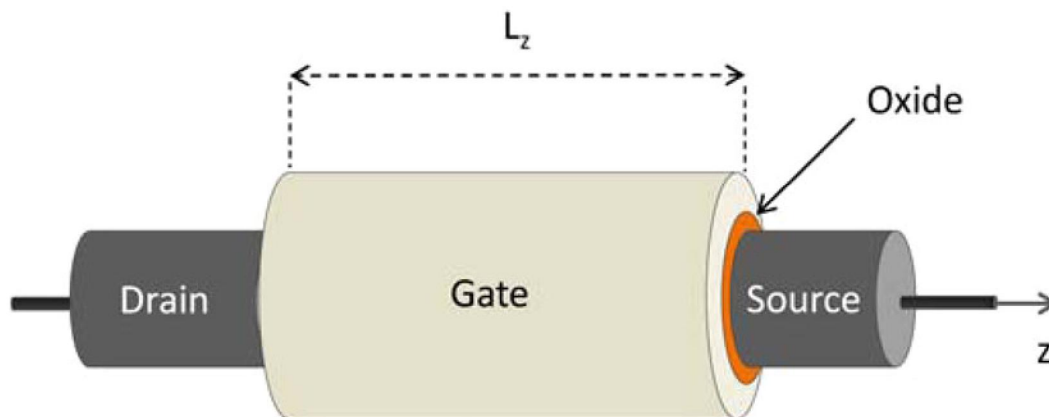
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REGULAR PAPERS

Evaluating the Frequency Response of Nanoscale Thermocouples Using Temperature Oscillations in Nanoscale Heaters G. P. Szakmany, A. O. Orlov, G. H. Bernstein, and W. Porod	567
Effect of a Clock System on Bis-Ferrocene Molecular QCA R. Wang, A. Pulimeno, M. R. Roch, G. Turvani, G. Piccinini, and M. Graziano	574
Integration of Carbon Nanotubes in Silicon Strip and Slot Waveguide Micro-Ring Resonators E. Durán-Valdeiglesias, W. Zhang, A. Noury, C. Alonso-Ramos, T. H. C. Hoang, S. Serna, X. Le Roux, E. Cassan, N. Izard, F. Sarti, U. Torrini, F. Biccari, A. Vinattieri, M. Balestrieri, A.-S. Keita, H. Yang, V. Bezugly, G. Cuniberti, A. Filoramo, M. Gurioli, and L. Vivien	583
Comprehensive Model for High-Speed Current-Mode Signaling in Next Generation MWCNT Bundle Interconnect Using FDTD Technique Y. Agrawal, M. G. Kumar, and R. Chandel	590
Ant Colony Optimization-Based Freeform Sources for Enhancing Nanolithographic Imaging Performance H.-F. Kuo and Frederick	599
Substrate Effect on Atomic Force Microscopy-Based Nanolithography of Graphene X. Tang and K. W. C. Lai	607
Formation of Nitrogen-Vacancy Centers in Homoepitaxial Diamond Thin Films Grown via Microwave Plasma-Assisted Chemical Vapor Deposition H. Watanabe, H. Umezawa, T. Ishikawa, K. Kaneko, S. Shikata, J. Ishi-Hayase, and K. M. Itoh	614
Electrical Characterization of Emerging Transistor Technologies: Issues and Challenges M. Haferlach, A. Pacheco, P. Sakalas, M. Alexandru, S. Hermann, T. Nardmann, M. Schröter, and M. Claus	619
An Explicit Quantum-Mechanical Compact Model for the $I - V$ Characteristics of Cylindrical Nanowire MOSFETs R. Ragi, R. V. T. da Nobrega, U. R. Duarte, and M. A. Romero	627
Logic Design Within Memristive Memories Using Memristor-Aided loGIC (MAGIC) N. Talati, S. Gupta, P. Mane, and S. Kvatinsky	635
Characterization of Effective Mobility and Its Degradation Mechanism in MoS ₂ MOSFETs T. Mori, N. Ninomiya, T. Kubo, N. Uchida, E. Watanabe, D. Tsuya, S. Moriyama, M. Tanaka, and A. Ando	651
A Continuous Compact Model Incorporating Higher-Order Correction for Junctionless Nanowire Transistors With Arbitrary Doping Profiles C. Hong, L. Yang, Q. Cheng, T. Han, J. B. Kuo, and Y. Chen	657
An HF-Free Etching of SiO ₂ for Soft Lithography S. Zhao, Q. Zhang, Y. Lv, and X. Wang	666

(Contents Continued on Page 566)

(Contents Continued from Page 565)

Large Magnetoresistance at Room Temperature in Ferromagnet/Topological Insulator Contacts	671
..... <i>S. Majumder, S. Guchhait, R. Dey, L. F. Register, and S. K. Banerjee</i>	
Methodology and Design of a Massively Parallel Memristive Stateful IMPLY Logic-Based Reconfigurable Architecture	675
..... <i>K. C. Rahman, D. Hammerstrom, Y. Li, H. Castagnaro, and M. A. Perkowski</i>	
Electrical and Electromechanical Properties of Stretchable Multilayer-Graphene/PDMS Composite Foils	687
..... <i>C. Acquarelli, L. Paliotta, A. Proietti, A. Tamburrano, G. De Bellis, and M. S. Sarto</i>	

About the cover: Schematic representation of a JL-NW-FET with the axis in the z -direction. See “An Explicit Quantum-Mechanical Compact Model for the $I - V$ Characteristics of Cylindrical Nanowire MOSFETs,” by Ragi *et al.*, p. 628.